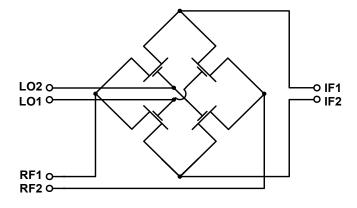


#### **Product Description**

The PE4141 is an ultra-high linearity passive broadband Quad MOSFET array with high dynamic range performance capable of operation up to 1.0 GHz. This quad array operates with differential signals at all ports (RF, LO, IF), allowing an analog multiplexer to be built that uses LO ports as digital controls, RF and IF port as single-ended or differential inputs/outputs. The PE4141 switches the differential input to the differential output at the LO switching rate. Packaged in an 8-lead MSOP package, the PE4141 is ideal for highly magnetic environments such as Magnetic Resonance Imaging (MRI).

The PE4141 is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram



# Product Specification

## PE4141

## Ultra-linear UltraCMOS™ Broadband Quad MOSFET Array Features

- Ultimate Quad MOSFET array
- Very high linearity
- Low magnetic
- Ideal for mixer applications
- Up/down conversion
- Low conversion loss
- High LO Isolation
- 8-lead MSOP package ideal for magnetic environments

#### **Applications**

The PE4141 is ideally suited for broadband analog multiplexer design in:

- Medical instrumentation
- Magnetic Resonance Imaging (MRI)
- Data acquisition and ADC/DAC muxing
- RF modulation/demodulation
- Precision instrumentation
- Analog or digital video switch matrices

Figure 2. Package Type

8-lead MSOP



Table 1. AC and DC Electrical Specifications @ +25 °C

Symbol	Characteristics	Test Conditions	Min	Тур	Max	Units
F <sub>TYP</sub>	Operating Frequency Range <sup>1</sup>		DC		1.0	GHz
V <sub>DS</sub>	Drain-Source Voltage	V <sub>GS</sub> = +3V, I <sub>DS</sub> = 40 mA	260	320	380	mV
V <sub>DS</sub> Match	Drain-Source Voltage Match			12	40	mV
V <sub>T</sub>	Threshold Voltage	V <sub>DS</sub> = 0.1V; per ASTM F617-00		-100		mV
R <sub>DS</sub>	Drain-Source 'ON' Resistance	V <sub>GS</sub> = +3V, I <sub>DS</sub> = 40 mA	6.5	7.75	9.5	Ω

Note: 1. Typical untested operating frequency range of Quad MOSFET transistors.



Figure 3. Pin Configuration (Top View)

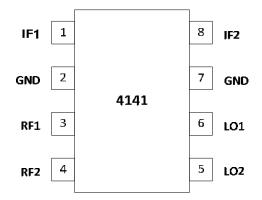


Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	IF1	IF Output Connection (Drain)
2	GND	Ground
3	RF1	RF Input Connection (Source)
4	RF2	RF Input Connection (Source)
5	LO2	LO Input Connection (Gate)
6	LO1	LO Input Connection (Gate)
7	GND	Ground
8	IF2	IF Output Connection (Drain)

Table 3. Absolute Maximum Ratings

Symbol	Parameters/ Conditions	Min	Max	Units
T <sub>ST</sub>	Storage temperature range	-65	150	°C
$T_OP$	Operating temperature range	0	70	ô
V <sub>DC + AC</sub>	Maximum DC plus peak AC voltage across Drain- Source		±3.3	V
$V_{\text{DC+AC}}$	Maximum DC plus peak AC voltage across Gate- Drain or Gate-Source		±4.2	٧
V <sub>ESD</sub>	ESD Sensitive Device		100	V

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

#### **Electrostatic Discharge (ESD) Precautions**

This MOSFET device has minimally protected inputs and is highly susceptible to ESD damage. When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices.

#### **Latch-Up Avoidance**

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

#### **Device Description**

The performance level of this MOSFET array is made possible by the very high linearity afforded by Peregrine's UltraCMOS™ process. The 8-lead MSOP package is suitable for highly magnetic applications including Magnetic Resonance Imaging (MRI.)

The PE4141 is an ideal MOSFET array core for a wide range of MOSFET array products, including module level solutions that incorporate baluns or other single-ended matching structures enabling three-port operation.

#### Marking

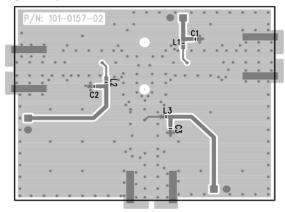
Packaged devices are marked with part number "4141", date code and lot code.



### **Evaluation Kit**

## Figure 4. Evaluation Board Layout

Peregrine Specification 101-0157-02



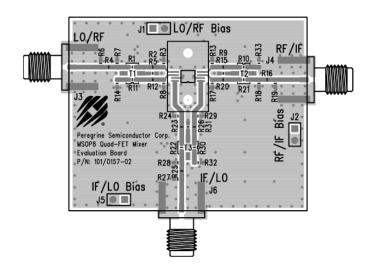
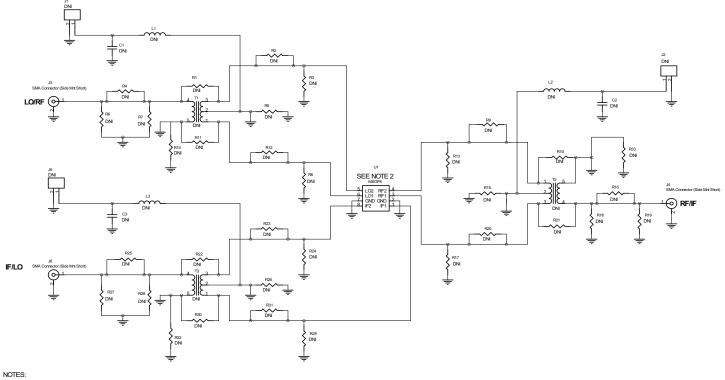


Figure 5. Evaluation Board Schematic

Peregrine Specification 102-0512-02



1. USE 101-0157-02 PCB.

2. DO NOT INSTALL U1 ACCORDING TO PIN 1 INDICATOR OF THE PCB SILKSCREEN. INSTALL U1 ROTATED BY 180 DEGREES.

Figure 6. Typical Schematic for a PCS Application

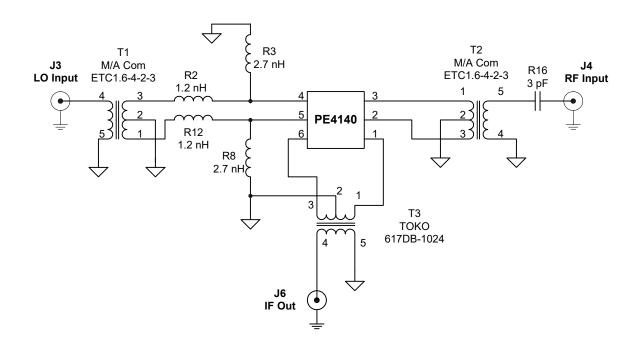


Table 4. Typical Performance in a PCS Application @ +25 °C

Parameter	Minimum	Typical	Maximum	Units
Frequency Range**				
LO	1630		2130	MHz
RF	1700		2200	MHz
IF		70		MHz
Conversion Loss**		0.5		-ID
(Includes balun losses)		8.5		dB
Isolation**				
LO-RF		36		dB
LO-IF		26		dB
Input IP3**		32		dBm
Input 1 dB Compression**		22		dBm

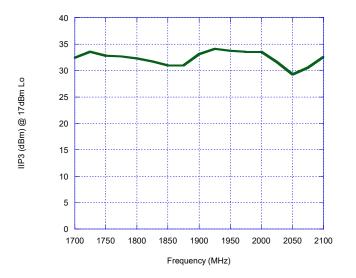
<sup>\*\*</sup> Data taken on an Evaluation Board narrow-band tuned to cover the PCS band, IF = 73MHz low-side, LO drive = 17dBm.



#### Typical Performance Plots in a PCS Application @ +25 °C (LO=17 dBm, IF=73 MHz Low-side)

#### Figure 7. IIP3 vs. Frequency

Figure 8. Conversion Loss vs. Frequency



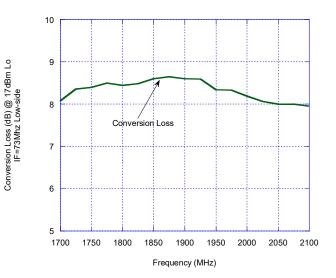


Figure 9. LO-RF & LO-IF Isolation

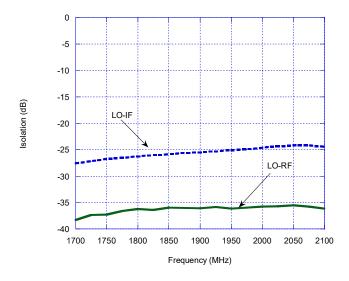
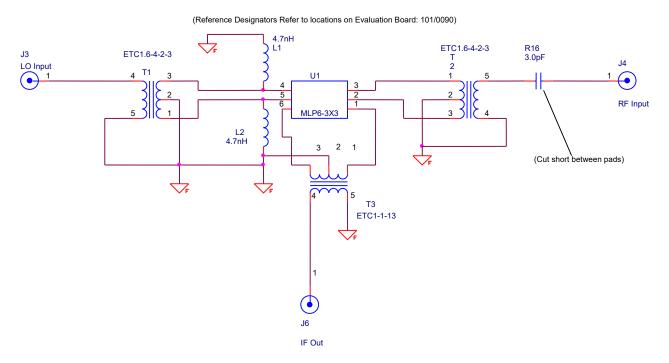


Figure 10. Typical Schematic for a CATV Application



Note: L1 and L2 provide LO port matching for optimum performance. Typical gate capacitance is approximately 2.5 pF.

Table 5. Typical Performance in a CATV Application @ +25 °C

Parameter	Minimum	Typical	Maximum	Units
Frequency Range**				
LO	1116	<del></del>	1926	MHz
RF	54	<del></del>	864	MHz
IF		1062		MHz
Conversion Loss**		6.5		dB
Isolation**				
LO-RF		40		dB
LO-IF		28		dB
Input IP3**		23		dBm
Input 1 dB Compression**		13		dBm

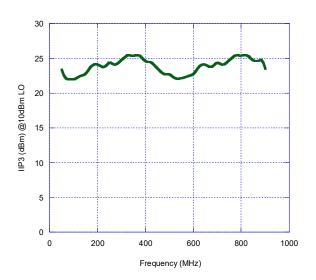
<sup>\*\*</sup> Data taken on an Evaluation Board tuned for a broadband CATV application, IF = 1062 MHz, RF drive = -5 dBm, LO drive = 10 dBm.



## Typical Performance Plots in a CATV Application @ +25 °C

### Figure 11. IIP3 vs. Frequency

Figure 12. Conversion Loss vs. Frequency



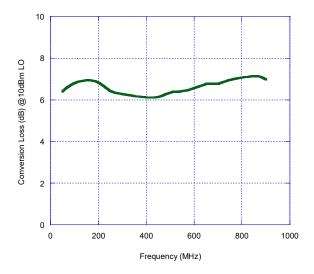
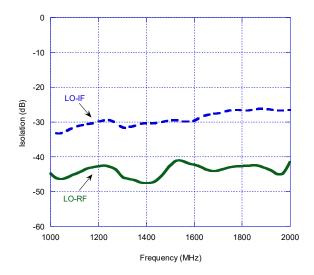


Figure 13. LO-RF & LO-IF Isolation





### Figure 14. Package Drawing

8-lead MSOP

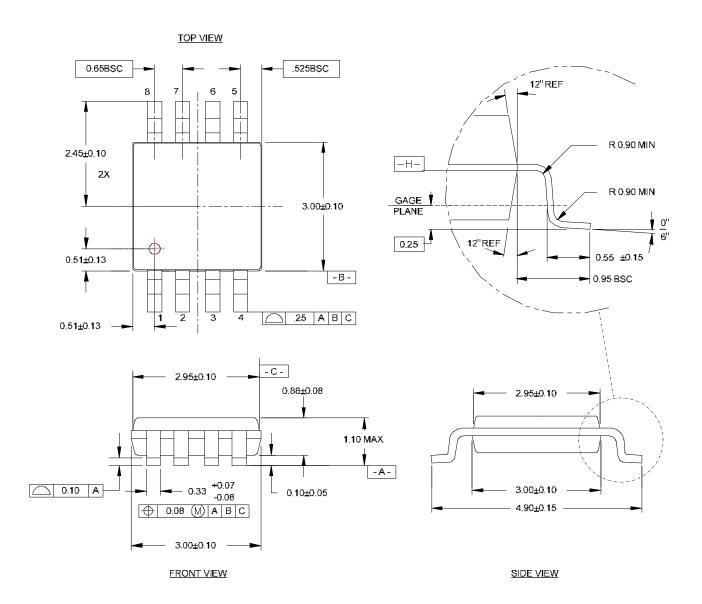
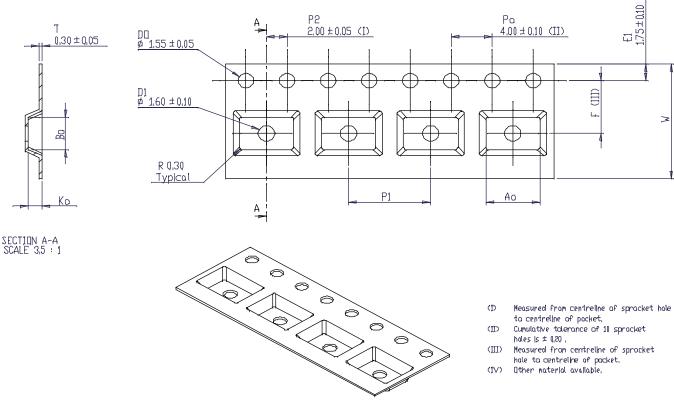




Figure 15. Tape and Reel Specification

8-lead MSOP



ALL DIMENSIONS IN MILLIMETRES UNLESS OTHERWISE STATED

Table 6. Dimensions

Dimension	MSOP-8
Ao	$5.30 \pm 0.1$
Во	$3.40 \pm 0.1$
Ko	$1.40 \pm 0.1$
F	$5.50 \pm 0.05$
$P_1$	8 ± 0.1
W	$12 \pm 0.3$

Table 7. Ordering Information

Order Codes	Description	Package	Shipping Method
4141-52	PE4141 quad MOSFET array	Green 8-lead MSOP	2000 units / T&R
PE4141B-W	PE4141 quad MOSFET array	Green 8-lead MSOP	2000 units / T&R
4141-00	PE4141 evaluation kit	Evaluation kit	1 / Box
EK4141-02	PE4141 evaluation kit	Evaluation kit	1 / Box

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